NSN 5961-01-194-1296

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Inclosure Material:

Metal

Overall Length:

1.550 inches

Overall Height:

0.450 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

140.0 collector-to-emitter, substaining voltage, base open-circuited and 160.0 collector to base voltage/static/emitter open and 10.0

emitter to base voltage, static, collector open

Power Rating Per Characteristic:

175.0 watts small-signal input power, common-collector absolute

Transfer Ratio:

10.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Precious Material And Location:

Pin terminal surfaces gold

Precious Material:

Gold

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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